EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L20	6009	(((carbon or dlc) near5 (film or layer)) with substrate with surface)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/09 10:56
L21	27	(((carbon or dlc) near5 (film or layer)) with substrate with surface) same (tft or (thin near film near transistor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/09 10:57
L22	21	(((carbon or dlc) near5 (film or layer)) near10 substrate with surface) same (tft or (thin near film near transistor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/09 10:57
L23	20	(((carbon or dlc) near5 (film or layer)) near10 substrate near10 surface) same (tft or (thin near film near transistor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/09 10:57
L24	25	(dlc or (carbon near2 film)) near10 (back near surface near2 substrate)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/09 10:59
L25	57	(dlc or (carbon near2 film)) near10 ((reverse or opposite or lower or first or second or back) near surface near2 substrate)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/09 11:00
L26	118	(dlc or (carbon near2 film)) near10 ((reverse or opposite or lower or first or second or back or upper or bottom or lower or both) near surface near2 substrate)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/09 11:01
L27	48	(dlc or (carbon near2 film)) near10 ((reverse or opposite or lower or first or second or back or upper or bottom or lower or both) near surface near2 substrate) and (tft or (thin near film near transistor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/09 11:02
L28	3594	(dlc or (carbon near3 film)).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/09 11:02

L29	110	(dlc or (carbon near3 film)).clm. and (tft or (thin near film near transistor)).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/09 11:10
L30	689	((back or rear or opposite or reverse or first or second or upper or lower or top or bottom) near surface) near5 substrate near10 carbon	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/09 11:11
L31	131	(((back or rear or opposite or reverse or first or second or upper or lower or top or bottom) near surface) near5 substrate near10 carbon).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/09 11:11
L32	65	(((back or rear or opposite or reverse or first or second or upper or lower or top or bottom) near surface) near5 substrate near10 carbon near10 (film or layer or laminate or laminating or laminated or lamination))).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/09 11:11
L33	6	(((back or rear or opposite or reverse or first or second or upper or lower or top or bottom) near surface) near5 substrate near10 carbon near10 (film or layer or laminate or laminating or laminated or lamination)).clm. and tft	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/09 11:14
L34	6	(((back or rear or opposite or reverse or first or second or upper or lower or top or bottom) near surface) near5 substrate near10 (dlc or carbon) near10 (film or layer or laminate or laminating or laminated or lamination)).clm. and tft	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/09 11:14

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	66280	((carbon or dlc) near2 (film or layer))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/09 10:45
L2	11524	((carbon or dlc) near2 (film or layer)) with substrate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/09 10:46
L3	1806	((carbon or dlc) near2 (film or layer)) with diamond with substrate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/09 10:46
L4	216	((carbon or dlc) near2 (film or layer)) with diamond with substrate and (tft or (thin near film near transistor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/09 10:46
L5	215	((carbon or dlc) near2 (film or layer)) near10 diamond with substrate and (tft or (thin near film near transistor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/09 10:46
L6	196	((carbon or dlc) near2 (film or layer)) near10 diamond near10 substrate and (tft or (thin near film near transistor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/09 10:48
L7	136	(((carbon or dlc) near2 (film or layer)) near10 diamond near10 substrate near10 surface) and (tft or (thin near film near transistor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/09 10:49
L8	3	(((carbon or dlc) near2 (film or layer)) near10 diamond near10 substrate near10 surface).clm. and (tft or (thin near film near transistor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/09 10:50
L9	9	(((carbon or dlc) near2 (film or layer)) near10 diamond near10 substrate).clm. and (tft or (thin near film near transistor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/09 10:51

L10	12	(((carbon or dlc) near2 (film or layer)) with diamond with substrate).clm. and (tft or (thin near film near transistor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/09 10:52
L11	53	(((carbon or dlc) near2 (film or layer)) with substrate).clm. and (tft or (thin near film near transistor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/09 10:52
L12	16	(((carbon or dlc) near2 (film or layer)) with substrate with surface).clm. and (tft or (thin near film near transistor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/09 10:52
L13	5	(((carbon or dlc) near2 (film or layer)) with substrate with surface).clm. and (tft or (thin near film near transistor)).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/09 10:53
L14	15	(((carbon or dlc) near2 (film or layer)) with substrate).clm. and (tft or (thin near film near transistor)).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/09 10:53
L15	29	(((carbon or dlc) near5 (film or layer)) with substrate).clm. and (tft or (thin near film near transistor)).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/09 10:54
L16	12	(((carbon or dlc) near5 (film or layer)) with substrate with surface).clm. and (tft or (thin near film near transistor)).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/09 10:56